

Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

[Comchip Technology](#)

[CDBF00340](#)

For any questions, you can email us directly:

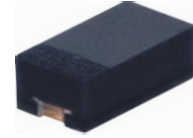
sales@integrated-circuit.com

SMD Schottky Barrier Diode



CDBF00340

$I_o = 30 \text{ mA}$
 $V_R = 40 \text{ Volts}$
RoHS Device

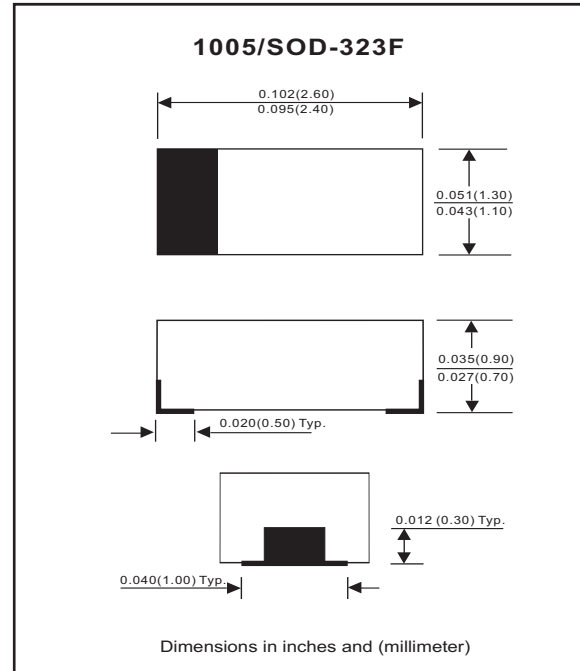


Features

- Designed for mounting on small surface.
- Extremely thin package.
- Low stored charge.
- Majority carrier conduction.

Mechanical data

- Case: 1005/SOD-323F standard package, molded plastic.
- Terminals: Gold plated, solderable per MIL-STD-750, method 2026.
- Polarity: Indicated by cathode band.
- Mounting position: Any
- Weight: 0.006 gram(approx.).



Maximum Rating (at $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Repetitive peak reverse voltage		V_{RRM}			45	V
Reverse voltage		V_R			40	V
Average forward current		I_o			30	mA
Forward current,surge peak	8.3 ms single half sine-wave superimposed on rate load(JEDEC method)	I_{FSM}		500		mA
Power Dissipation		P_d			200	mW
Storage temperature		T_{STG}	-40		+125	$^\circ\text{C}$
Junction temperature		T_j			+125	$^\circ\text{C}$

Electrical Characteristics (at $T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F = 1 \text{ mA DC}$	V_F			0.37	V
Reverse current	$V_R = 30\text{V}$ $V_R = 40\text{V}$	I_R			0.50 1.00	μA
Capacitance between terminals	$F = 1 \text{ MHz}$ and 1 VDC reverse voltage	C_T		1.5		pF

SMD Schottky Barrier Diode



RATING AND CHARACTERISTIC CURVES (CDBF00340)

Fig. 1 - Forward characteristics

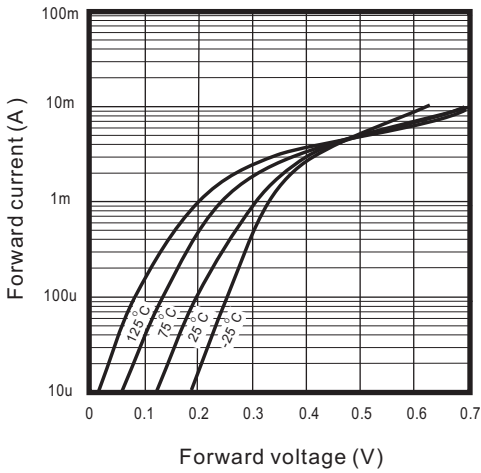


Fig. 2 - Reverse characteristics

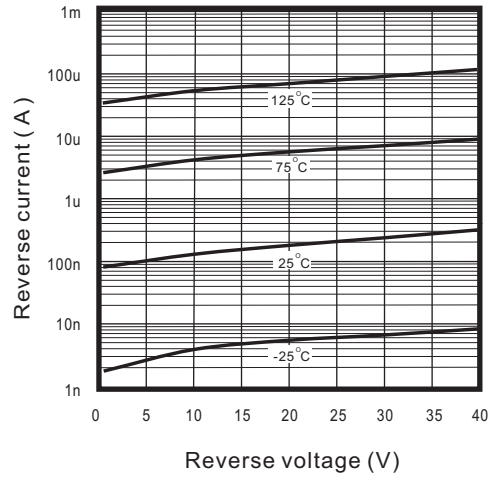


Fig.3 - Capacitance between terminals characteristics

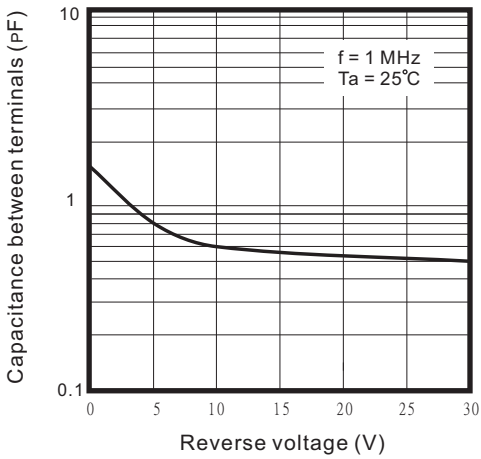


Fig.4 - Current derating curve

